

TOSHIBA Photocoupler GaAs Ired & Photo-MOS FET

# TLP206G

PBX

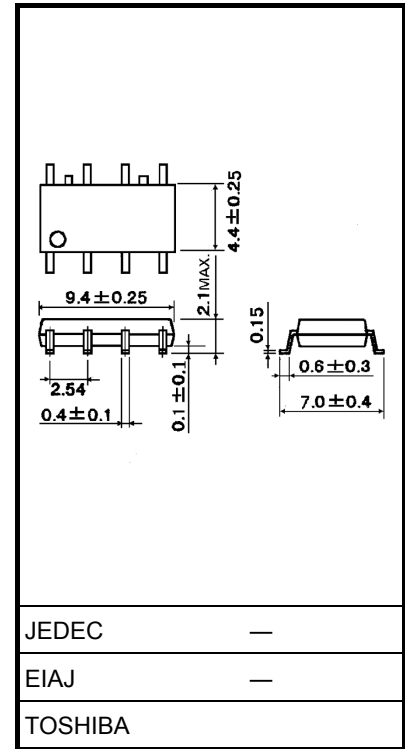
Modem · FAX Card

Measurement Instrument

The TOSHIBA TLP206G consists of gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a 8 pin SOP. The TLP206G is a 2-Form-A switch which is suitable for replacement of mechanical relays in many application.

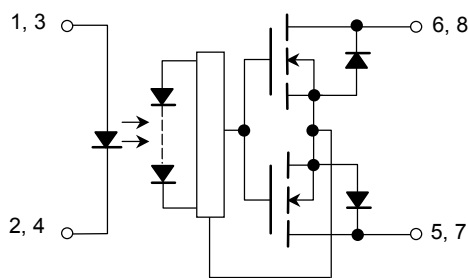
- SOP 8 pin (2.54SOP8): 2-Form-A
- Peak off-state voltage: 350V(min)
- Trigger LED current: 3mA(max)
- On-state current: 120mA(max)
- On-state resistance: 35Ω(max)
- Isolation voltage: 1500V<sub>rms</sub>(min)
- UL recognized: UL1577, file no.E67349
- BSI approved: BS EN60065: 2002, certificate no.8753  
BS EN60950-1: 2002, certificate no.8754
- SEMKO approved: SS EN60065  
SS EN60950
- Option(V4)type  
TUV approved: DIN EN 60747-5-2,  
certificate No. 40009351

Unit in mm

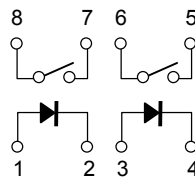


Weight: 0.2 g

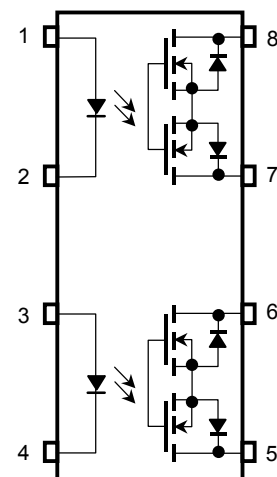
## Schematic



2-Form-A



## Pin Configuration (top view)



- 1, 3: Anode
- 2, 4: Cathode
- 5: Drain D1
- 6: Drain D2
- 7: Drain D3
- 8: Drain D4

## Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
LED	Forward current	$I_F$	50	mA	
	Forward current derating (Ta ≥ 25°C)	$\Delta I_F / ^\circ\text{C}$	-0.5	mA / °C	
	Pulse forward current (100μs pulse, 100pps)	$I_{FP}$	1	A	
	Reverse voltage	$V_R$	5	V	
	Junction temperature	$T_j$	125	°C	
Detector	Off-state output terminal voltage	$V_{OFF}$	350	V	
	On-state current	Both channel (Note 1)	$I_{ON}$	100	mA
		One channel		120	
	On-state RMS current derating (Ta ≥ 25°C)	Both channel (Note 1)	$\Delta I_{ON} / ^\circ\text{C}$	-1.0	mA / °C
		One channel		-1.2	
Junction temperature	$T_j$	125	°C		
Storage temperature range		$T_{stg}$	-55~125	°C	
Operating temperature range		$T_{opr}$	-40~85	°C	
Lead soldering temperature (10 s)		$T_{sol}$	260	°C	
Isolation voltage (AC, 1 min., R.H. ≤ 60%) (Note 2)		$BV_S$	1500	$V_{rms}$	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1): Two channels operating simultaneously.

(Note 2): Device considered a two-terminal device: Pins 1,2,3 and 4 shorted together and pins 5,6,7 and 8 shorted together.

## Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	$V_{DD}$	—	—	280	V
Forward current	$I_F$	5	7.5	25	mA
On-state current	$I_{ON}$	—	—	100	mA
Operating temperature	$T_{opr}$	-20	—	65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

## Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	$V_F$	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse current	$I_R$	$V_R = 5 \text{ V}$	—	—	10	$\mu\text{A}$
	Capacitance	$C_T$	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
Detector	Off-state current	$I_{OFF}$	$V_{OFF} = 350 \text{ V}$	—	—	1	$\mu\text{A}$
	Capacitance	$C_{OFF}$	$V = 0, f = 1 \text{ MHz}$	—	40	—	pF

## Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Trigger LED current	$I_{FT}$	$I_{ON} = 120 \text{ mA}$	—	1	3	mA
On-state resistance	$R_{ON}$	$I_{ON} = 120 \text{ mA}, I_F = 5 \text{ mA}$	—	22	35	$\Omega$

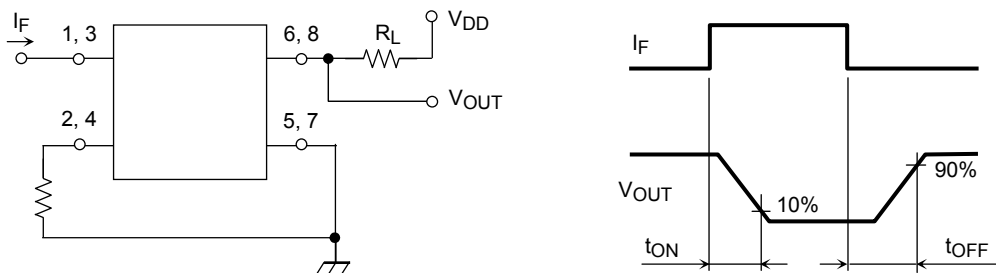
## Isolation Characteristics (Ta = 25°C)

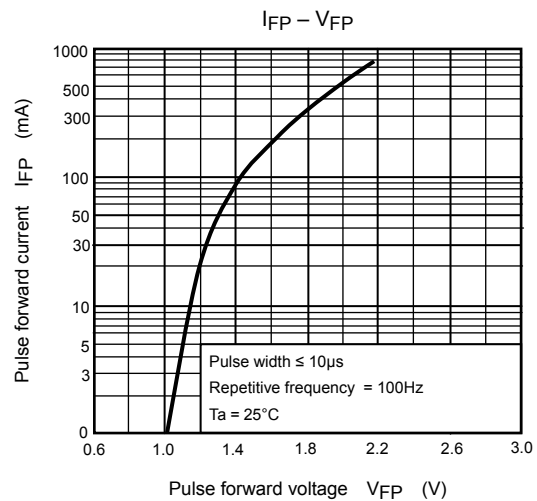
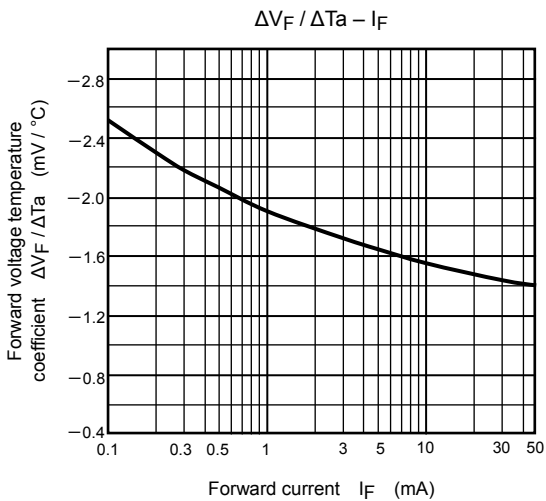
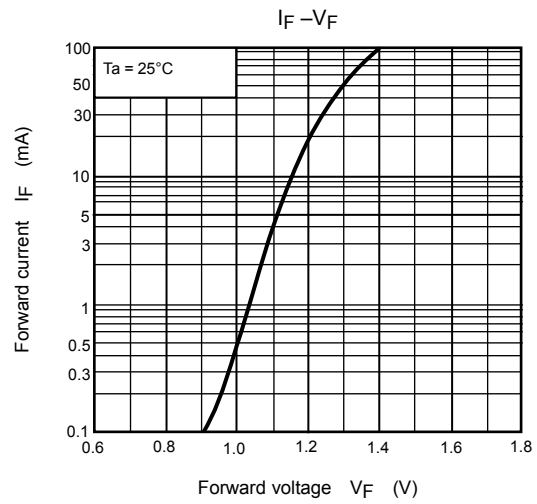
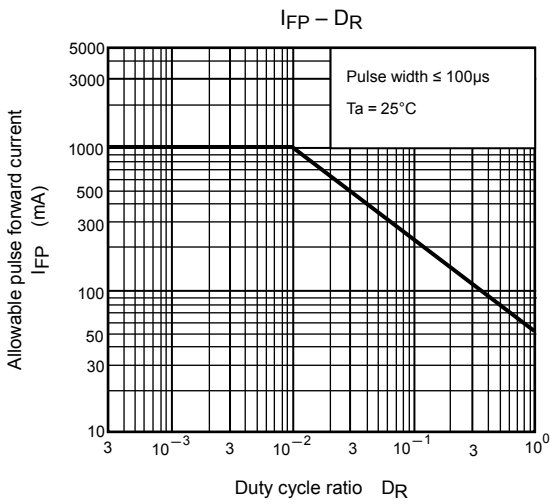
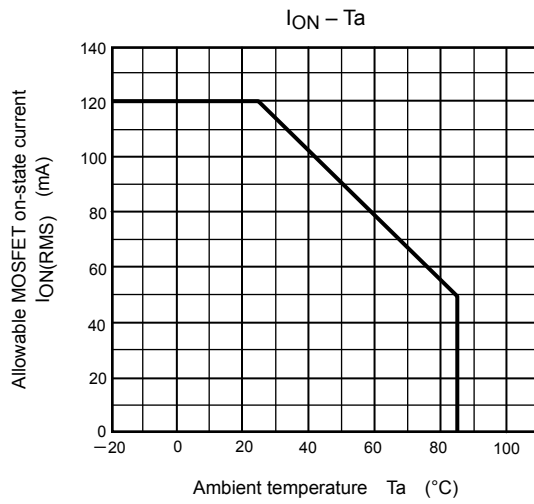
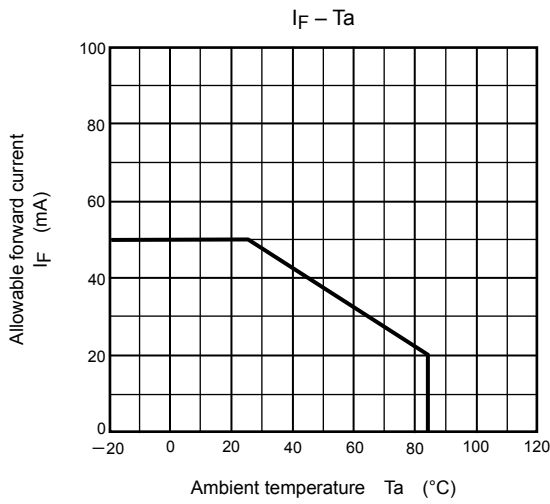
Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Capacitance input to output	$C_S$	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation resistance	$R_S$	$V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$	$5 \times 10^{10}$	$10^{14}$	—	$\Omega$
Isolation voltage	$BV_S$	AC, 1 minute	1500	—	—	$V_{rms}$
		AC, 1 second, in oil	—	3000	—	
		DC, 1 minute, in oil	—	3000	—	$V_{dc}$

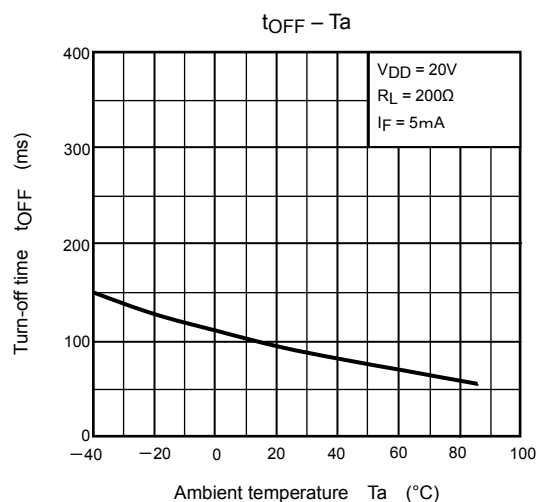
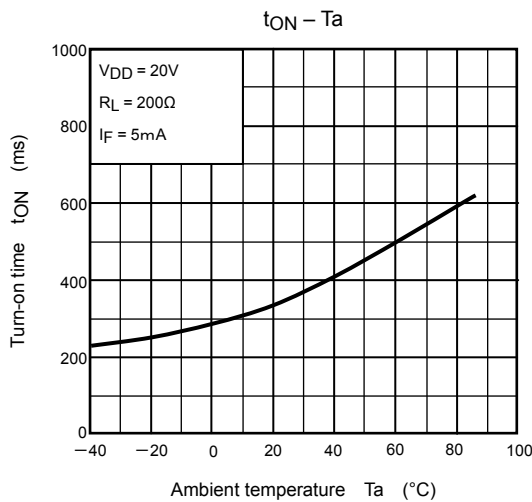
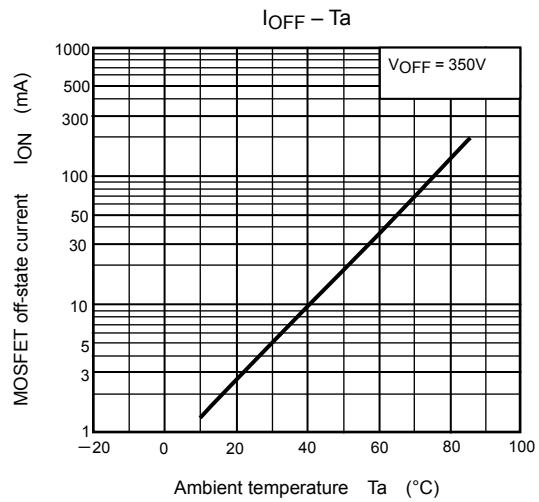
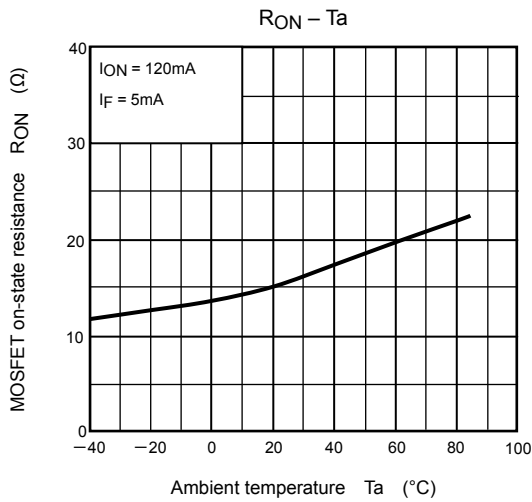
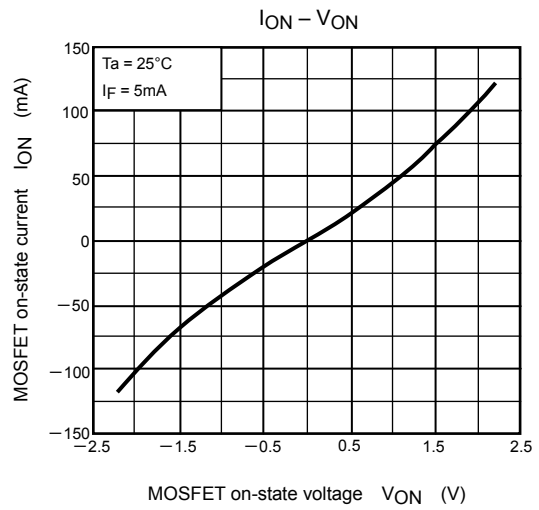
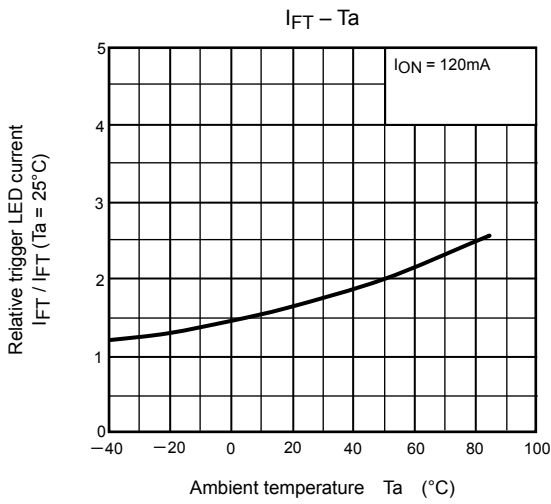
## Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Turn-on time	$t_{ON}$	$R_L = 200 \Omega$ (Note 3) $V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$	—	0.3	1	ms
Turn-off time	$t_{OFF}$		—	0.1	1	

(Note 3): Switching time test circuit







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20070701-EN

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